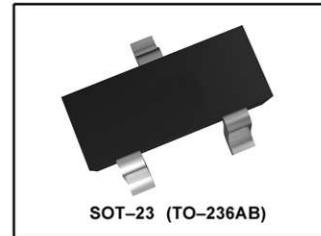
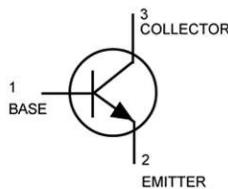


NPN Silicon

● MAXIMUM RATINGS

Rating	Symbol	2222	2222A	Unit
Collector-Emitter Voltage	V_{CEO}	30	40	Vdc
Collector-Base Voltage	V_{CBO}	60	75	Vdc
Emitter-Base Voltage	V_{EBO}	5.0	6.0	Vdc
Collector Current — Continuous	I_C	600	600	mAdc

● THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (1) $T_A = 25^\circ\text{C}$	P_D	225	mW
Derate above 25°C		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	R_{BJA}	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (2) $T_A = 25^\circ\text{C}$	P_D	300	mW
Derate above 25°C		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	R_{BJA}	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$

● DEVICE MARKING

MMBT2222LT1 = M1B; MMBT2222ALT1 = 1P;

● ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector-Emitter Breakdown Voltage ($I_C = 10 \text{ mA}, I_B = 0$)	MMBT2222 MMBT2222A	$V_{(BR)CEO}$ 40	30	—
Collector-Base Breakdown Voltage ($I_C = 10 \mu\text{A}, I_E = 0$)	MMBT2222 MMBT2222A	$V_{(BR)CBO}$ 75	60	—
Emitter-Base Breakdown Voltage ($I_E = 10 \mu\text{A}, I_C = 0$)	MMBT2222 MMBT2222A	$V_{(BR)EBO}$ 6.0	5.0	—
Collector Cutoff Current ($V_{CE} = 60 \text{ Vdc}, I_{EB(off)} = 3.0 \text{ Vdc}$)	MMBT2222A	I_{CEX}	—	nAdc
Collector Cutoff Current ($V_{CB} = 50 \text{ Vdc}, I_E = 0$)	MMBT2222	I_{CBO}	—	μAdc
($V_{CB} = 60 \text{ Vdc}, I_E = 0$)	MMBT2222A		—	0.01
($V_{CB} = 50 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$)	MMBT2222		—	10
($V_{CB} = 60 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}$)	MMBT2222A		—	10
Emitter Cutoff Current ($V_{EB} = 3.0 \text{ Vdc}, I_C = 0$)	MMBT2222A	I_{EBO}	—	nAdc
Base Cutoff Current ($V_{CE} = 60 \text{ Vdc}, V_{EB(off)} = 3.0 \text{ Vdc}$)	MMBT2222A	I_{BL}	—	20

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

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● ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
ON CHARACTERISTICS					
DC Current Gain ($I_c = 0.1 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}$)	MMBT2222A only	h_{FE}	35	—	—
($I_c = 1.0 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}$)			50	—	—
($I_c = 10 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}$)			75	—	—
($I_c = 10 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}, T_A = -55^\circ\text{C}$)			35	—	—
($I_c = 150 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}$) (3)			100	300	—
($I_c = 150 \text{ mA}_\text{dc}, V_{CE} = 1.0 \text{ V}_\text{dc}$) (3)			50	—	—
($I_c = 500 \text{ mA}_\text{dc}, V_{CE} = 10 \text{ V}_\text{dc}$) (3)	MMBT2222		30	—	—
	MMBT2222A		40	—	—
Collector-Emitter Saturation Voltage (3)		$V_{CE(\text{sat})}$			Vdc
($I_c = 150 \text{ mA}_\text{dc}, I_B = 15 \text{ mA}_\text{dc}$)	MMBT2222		—	0.4	
	MMBT2222A		—	0.3	
($I_c = 500 \text{ mA}_\text{dc}, I_B = 50 \text{ mA}_\text{dc}$)	MMBT2222		—	1.6	
	MMBT2222A		—	1.0	
Base-Emitter Saturation Voltage		$V_{BE(\text{sat})}$			Vdc
($I_c = 150 \text{ mA}_\text{dc}, I_B = 15 \text{ mA}_\text{dc}$)	MMBT2222		—	1.3	
	MMBT2222A		0.6	1.2	
($I_c = 500 \text{ mA}_\text{dc}, I_B = 50 \text{ mA}_\text{dc}$)	MMBT2222		—	2.6	
	MMBT2222A		—	2.0	

SMALL-SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product(4) ($I_c = 20 \text{ mA}_\text{dc}, V_{CE} = 20 \text{ V}_\text{dc}, f = 100 \text{ MHz}$)	MMBT2222	f_T	250	—	MHz
	MMBT2222A		300	—	
Output Capacitance($V_{CB} = 10 \text{ V}_\text{dc}, I_E = 0, f = 1.0 \text{ MHz}$)		$C_{o\text{bo}}$	—	8.0	pF
Input Capacitance ($V_{EB} = 0.5 \text{ V}_\text{dc}, I_c = 0, f = 1.0 \text{ MHz}$)	MMBT2222	$C_{i\text{bo}}$	—	30	pF
($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 1.0 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A		—	25	
($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 10 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A	h_{ie}	2.0	8.0	kΩ
	MMBT2222A		0.25	1.25	
Voltage Feedback Ratio($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 1.0 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A	h_{re}	—	8.0	$\times 10^{-4}$
($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 10 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A		—	4.0	
Small-Signal Current Gain($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 1.0 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A	h_{fe}	50	300	—
($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 10 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A		75	375	
Output Admittance($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 1.0 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A	h_{oe}	5.0	35	μmhos
($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 10 \text{ mA}_\text{dc}, f = 1.0 \text{ kHz}$)	MMBT2222A		25	200	
Curren Base Time Constant					
($V_{CB} = 20 \text{ V}_\text{dc}, I_E = 20 \text{ mA}_\text{dc}, f = 31.8 \text{ MHz}$)	MMBT2222A	r_b, C_c	—	150	ps
Noise Figure($V_{CE} = 10 \text{ V}_\text{dc}, I_c = 10 \mu\text{A}_\text{dc}, R_s = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz}$)	MMBT2222A	NF	—	4.0	dB

● SWITCHING CHARACTERISTICS

Delay Time	($V_{CC} = 30 \text{ V}_\text{dc}, V_{EB(\text{off})} = -0.5 \text{ V}_\text{dc}$)	t_d	—	10	ns
Rise Time	($I_c = 150 \text{ mA}_\text{dc}, I_{B1} = 15 \text{ mA}_\text{dc}$)	t_r	—	25	
Storage Time	($V_{CC} = 30 \text{ V}_\text{dc}, I_c = 150 \text{ mA}_\text{dc}$)	t_s	—	225	ns
Fall Time	($I_{B1} = I_{B2} = 15 \text{ mA}_\text{dc}$)	t_f	—	60	

3. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

4. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.

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SWITCHING TIME EQUIVALENT TEST CIRCUITS

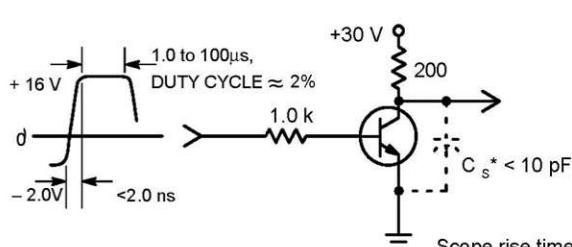


Figure 1. Turn-On Time

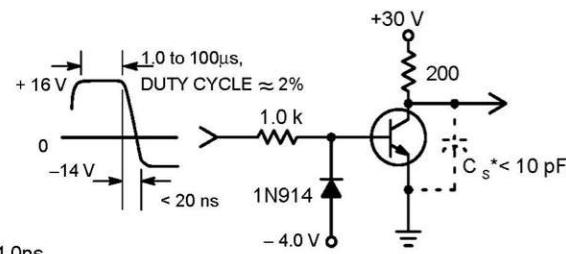


Figure 2. Turn-Off Time

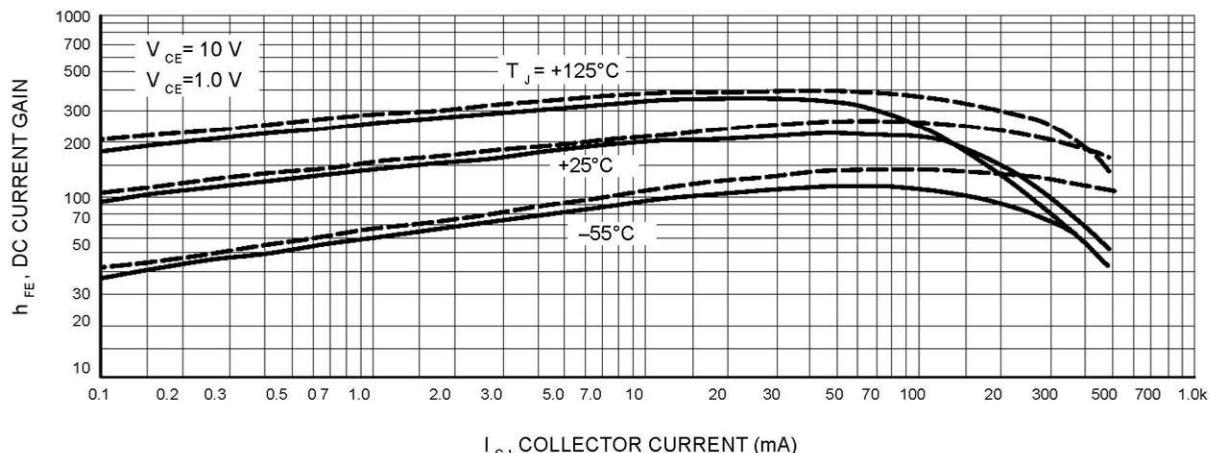


Figure 3. DC Current Gain

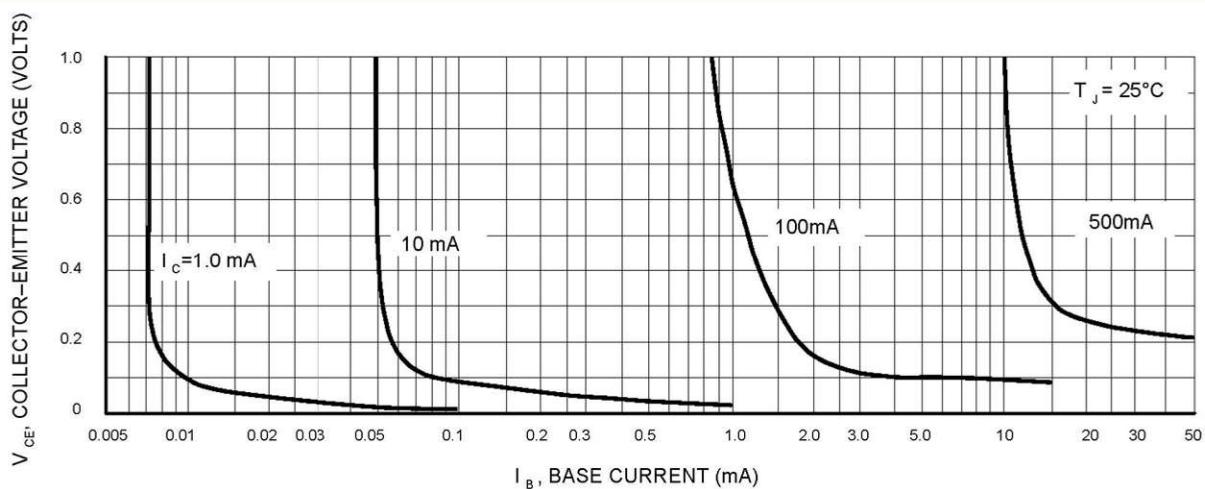


Figure 4. Collector Saturation Region

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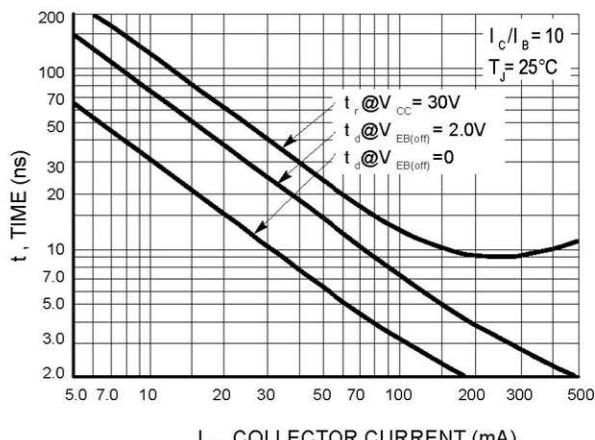


Figure 5. Turn-On Time

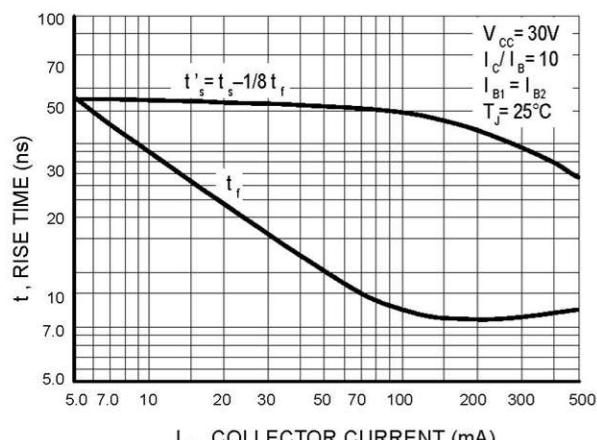


Figure 6. Turn-Off Time

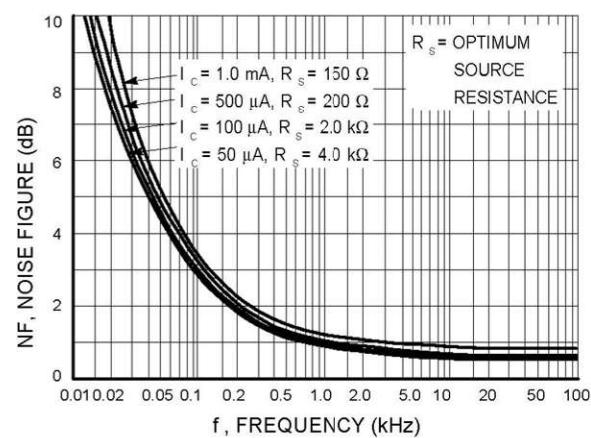


Figure 7. Frequency Effects

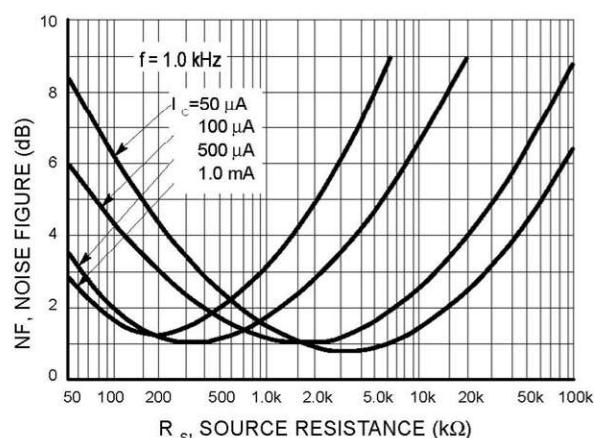


Figure 8. Source Resistance Effects

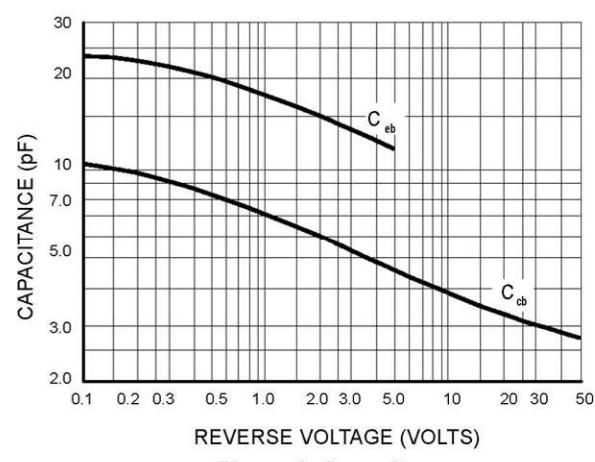


Figure 9. Capacitance

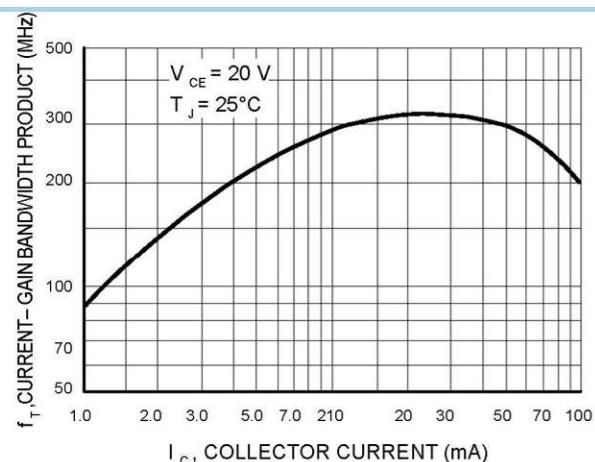


Figure 10. Current-Gain Bandwidth Product

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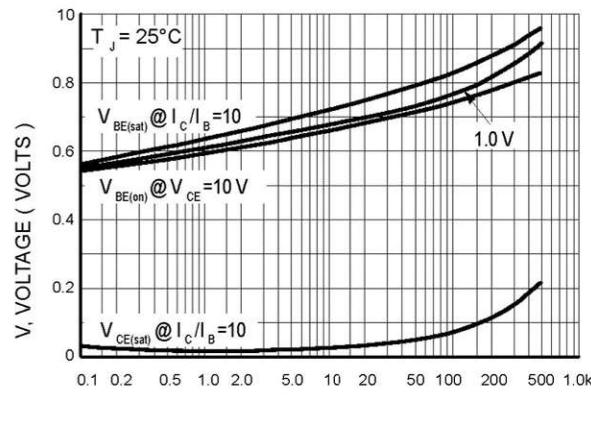


Figure 11. "On" Voltages

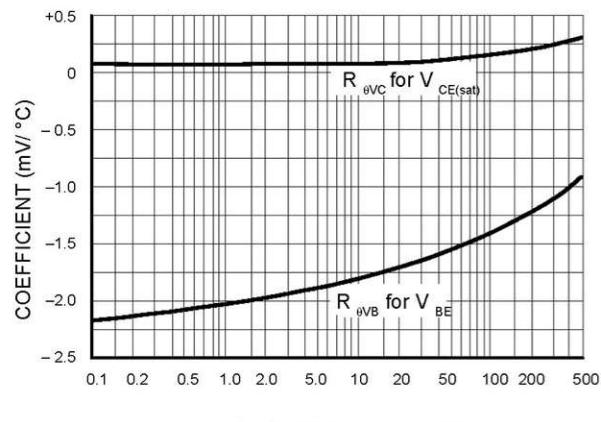


Figure 12. Temperature Coefficients